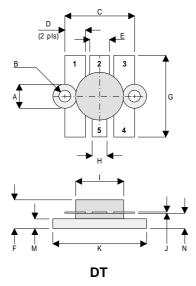


METAL GATE RF SILICON FET

MECHANICAL DATA



PIN 1 SOURCE (COMMON) PIN 2 **GATE**

SOURCE (COMMON) PIN 4 SOURCE (COMMON) PIN₃

PIN 5 DRAIN

DIM	mm	Tol.	Inches	Tol.
Α	6.35 DIA	0.13	0.250 DIA	0.005
В	3.17 DIA	0.13	0.125 DIA	0.005
С	18.41	0.25	0.725	0.010
D	5.46	0.13	0.215	0.005
Е	5.21	0.13	0.205	0.005
F	7.62	MAX	0.300	MAX
G	21.59	0.38	0.850	0.015
Н	3.94	0.13	0.155	0.005
I	12.70	0.13	0.500	0.005
J	0.13	0.03	0.005	0.001
K	24.76	0.13	0.975	0.005
M	2.59	0.13	0.102	0.005
N	4.06	0.25	0.160	0.010

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET 80W - 28V - 175MHzSINGLE ENDED

FEATURES

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- LOW C_{rss}
- SIMPLE BIAS CIRCUITS
- LOW NOISE
- HIGH GAIN 16 dB MINIMUM

APPLICATIONS

 HF/VHF COMMUNICATIONS from 1 MHz to 175 MHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

$\overline{P_D}$	Power Dissipation	175W
BV _{DSS}	Drain – Source Breakdown Voltage	70V
BV_{GSS}	Gate – Source Breakdown Voltage	±20V
I _{D(sat)}	Drain Current	20A
T _{stg}	Storage Temperature	−65 to 150°C
T _j	Maximum Operating Junction Temperature	200°C

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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Document Number 6257 Issue 1

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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
B\/	Drain-Source	V _{GS} = 0	I _D = 100mA	70			V
BV _{DSS}	Breakdown Voltage	v _{GS} = 0	ID = 100IIIA	70			V
1	Zero Gate Voltage	V _{DS} = 28V	V _{GS} = 0			4	mA
IDSS	Drain Current					4	IIIA
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	V _{DS} = 0			1	μΑ
V _{GS(th)}	Gate Threshold Voltage *	I _D = 10mA	$V_{DS} = V_{GS}$	1		7	V
9 _{fs}	Forward Transconductance *	V _{DS} = 10V	I _D = 4A	3.2			S
G _{PS}	Common Source Power Gain	P _O = 80W		16			dB
η	Drain Efficiency	V _{DS} = 28V	$I_{DQ} = 0.4A$	50			%
VSWR	Load Mismatch Tolerance	f = 175MHz	7	20:1			_
C _{iss}	Input Capacitance	V _{DS} = 28V	$V_{GS} = -5V$ f = 1MHz			240	pF
C _{oss}	Output Capacitance	V _{DS} = 28V	$V_{GS} = 0$ $f = 1MHz$			120	pF
C _{rss}	Reverse Transfer Capacitance	V _{DS} = 28V	$V_{GS} = 0$ f = 1MHz			10	pF

^{*} Pulse Test: Pulse Duration = 300 μs , Duty Cycle ≤ 2%

HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

THERMAL DATA

R _{THj-case}	Thermal Resistance Junction – Case	Max. 1.0°C / W
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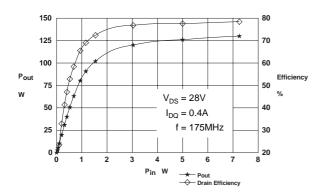


Figure 1 – Power Output and Efficiency vs. Power Input.

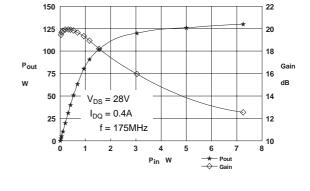


Figure 2 – Power Output & Gain vs. Power Input.

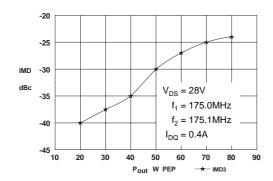


Figure 3 – IMD vs. Output Power.

D1004UK OPTIMUM SOURCE AND LOAD IMPEDANCE

Frequency	Z _S	Z_{L}
MHz	Ω	Ω
175MHz	2.2 + j1.9	3.2 - j0.5

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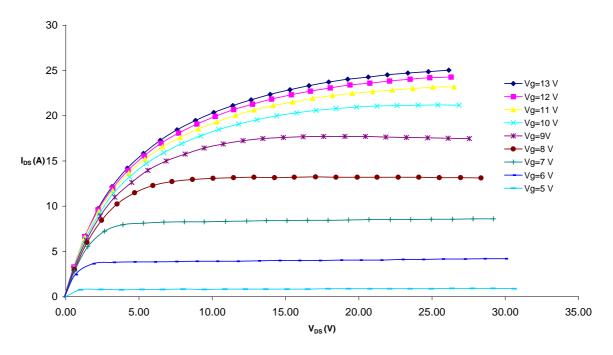


Figure 4 – Typical IV Characteristics.

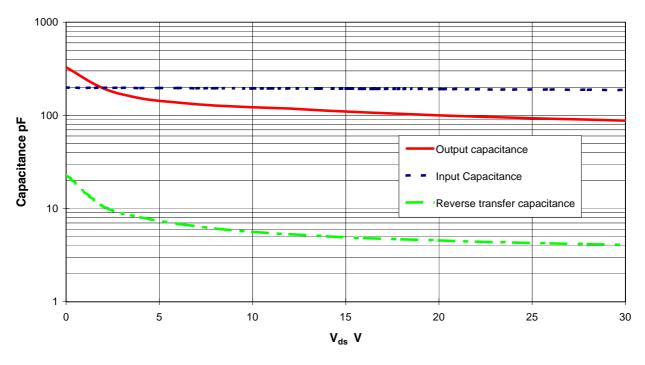


Figure 5 – Typical CV Characteristics.

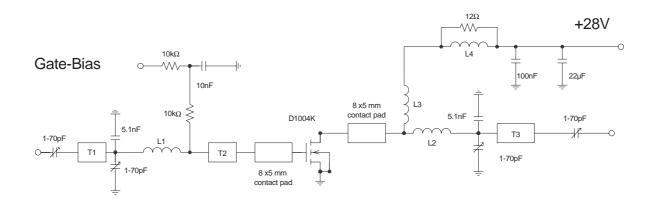
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D1004UK 175MHz TEST FIXTURE

Substrate 1.6mm PTFE/ glass, Er= 2.5 All microstrip lines W=4.4mm

T1 7.5mm T2 6mm

T3 8mm

L1 Hairpin loop 16swg 13mm dia

L2 Hairpin loop 16swg 11mm dia

L3 10 turns 18swg enamelled copper wire, 4mm i.d.

L4 12 turns 18swg enamelled copper wire on 22.7mm o.d. ferrite core

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